

## Supporting information for:

### **Tuning electronic structure of BaTiO<sub>3</sub> for enhanced photocatalytic performance using cation-anion codoping: A first-principles study**

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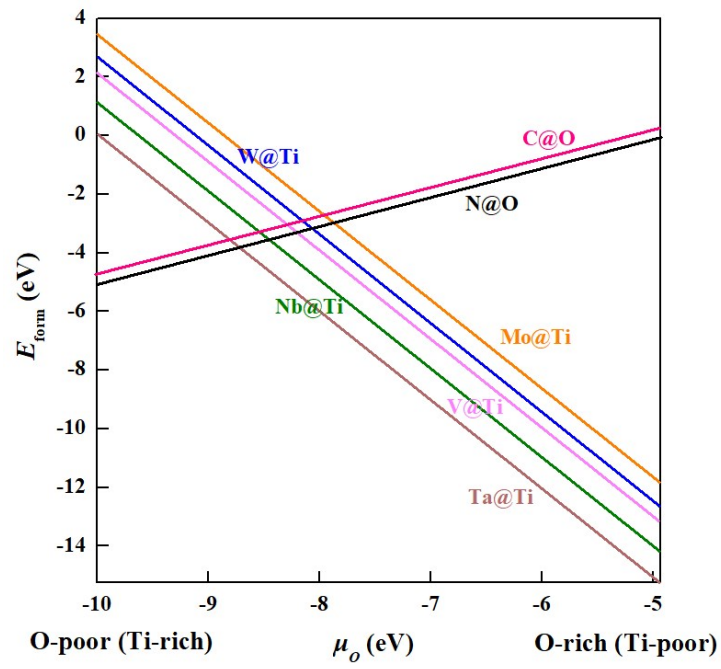
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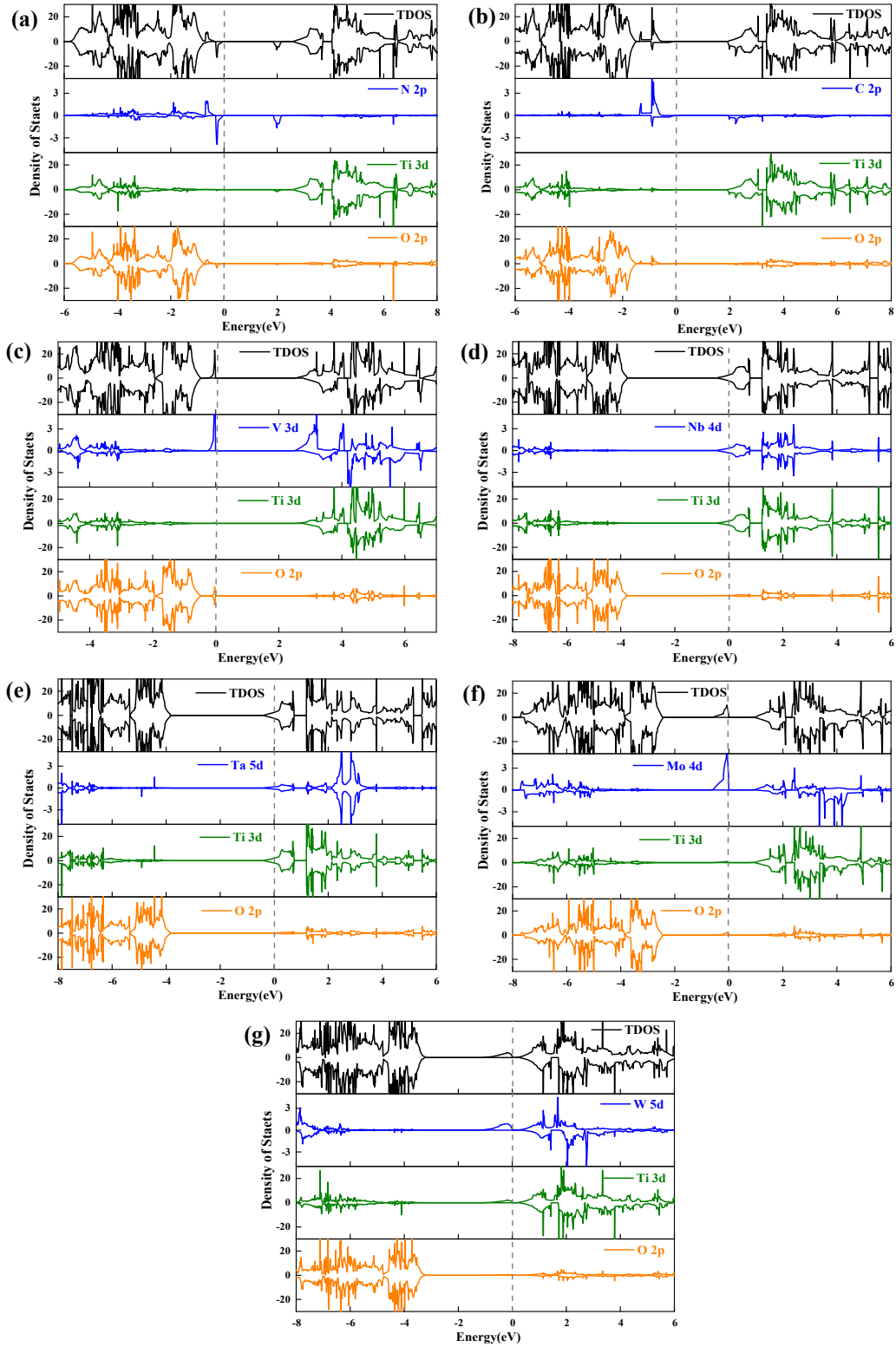
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**Table S1.** Calculated formation energies (in eV) for TM/X monodoped BaTiO<sub>3</sub> under O-rich and Ti-rich growth conditions.

<b>E<sub>form</sub> (2×2×2)</b>	<b>TM/X</b>	<b>Ti-rich</b>	<b>O-rich</b>
<b>TM@Ti</b>	V	2.06	-13.12
	Nb	1.04	-14.14
	Ta	-0.06	-15.24
	Mo	3.45	-11.73
	W	2.63	-12.55
<b>X@O</b>	N	-5.07	-0.01
	C	-4.68	0.38



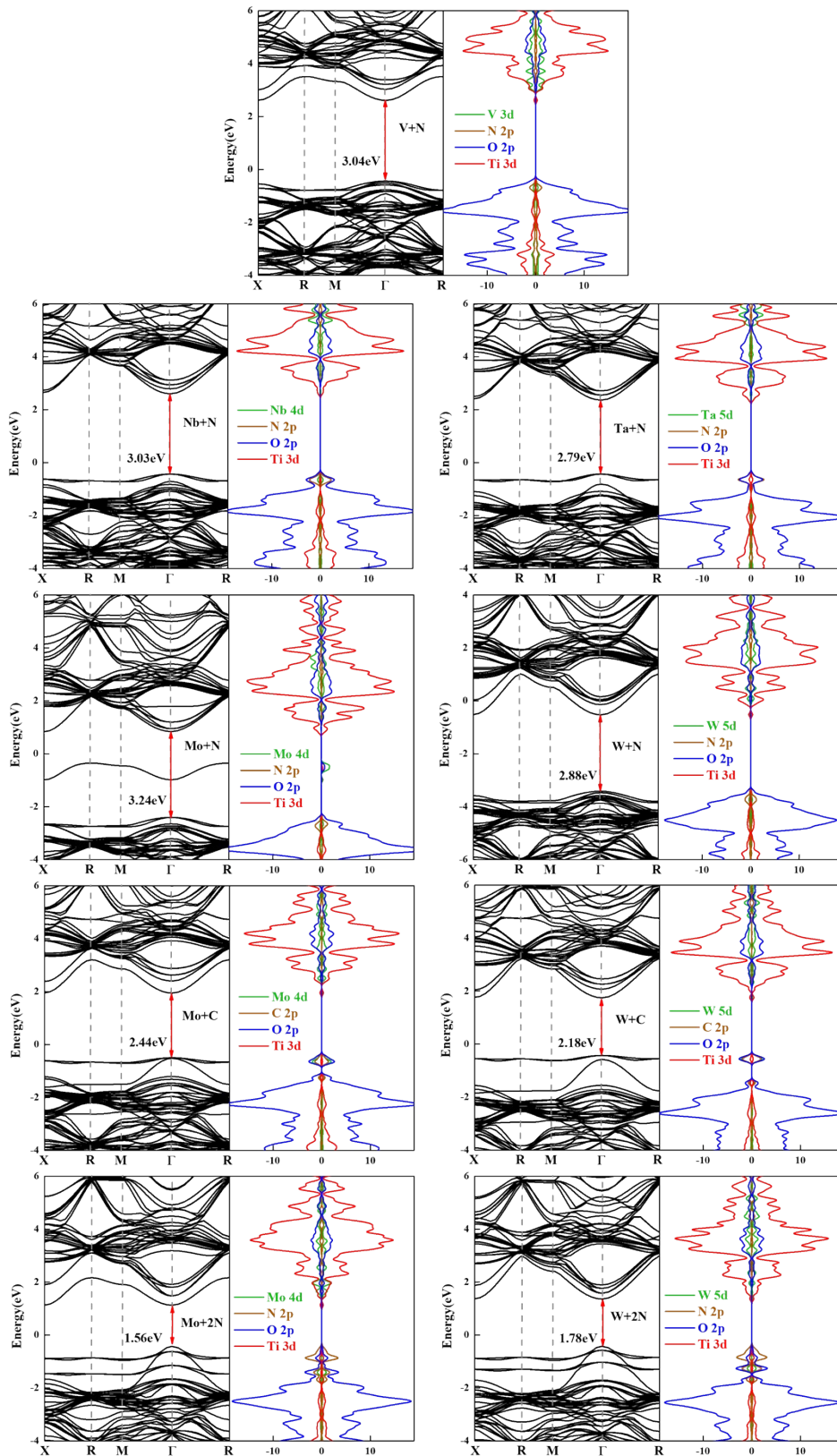
**Fig. S1.** Formation energies (eV)  $E_{\text{form}}$  as a function of the oxygen chemical potential for N-, C-, V-, Nb-, Ta-, Mo-, and W-monodoped BaTiO<sub>3</sub>.



**Fig. S2.** The calculated density of states for (a) N-doped, (b) C-doped (c) V-doped, (d) Nb-doped, (e) Ta-doped, (f) Mo-doped and (g) W-doped BaTiO<sub>3</sub>. The dashed line is the Fermi level.

**Table S2.** The fully optimized crystal parameters and band gaps of (TM+X)-codoped BaTiO<sub>3</sub>

	Relaxed parameters			Band gap
	a	b	c	
V-N	8.1425	7.9659	7.9659	3.04
Nb-N	8.1437	8.0141	8.0141	3.03
Ta-N	8.1035	8.0163	8.0163	2.79
Mo-N	8.0975	8.0094	8.0094	3.24
W-N	8.0621	8.0142	8.0142	2.88
Mo-C	8.2046	7.9919	7.9919	2.44
W-C	8.1991	7.9899	7.9899	2.18
Mo-2N	8.0193	8.0266	8.0266	1.56
W-2N	8.0230	8.0237	8.0237	1.78



**Figure S3.** Computed band structure and density of states for fully relaxed (TM+X)-codoped BaTiO<sub>3</sub>